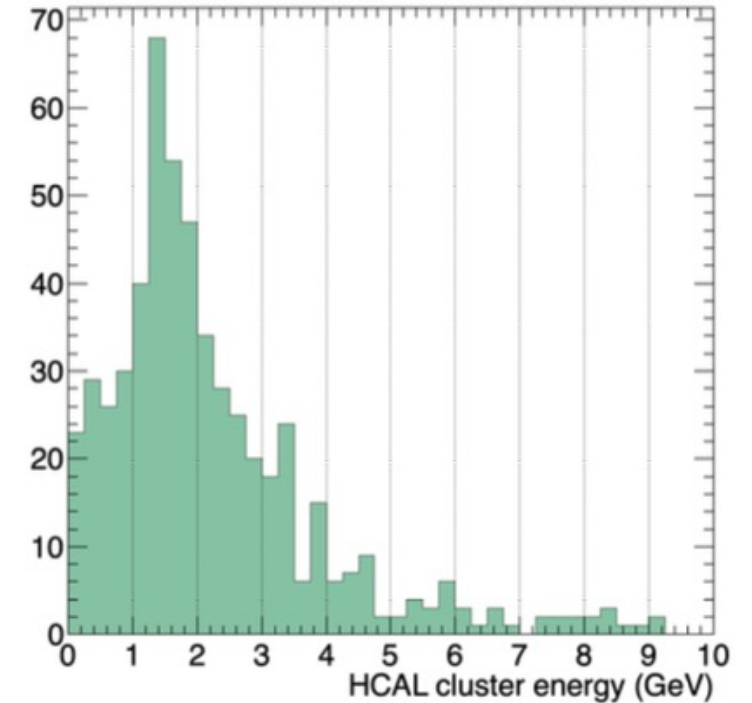


Noise and Radiation Damages in STAR FCS



Akio Ogawa

2024/04/24

EIC Experimental Equipment DAQ and Electrical Engineering round table

STAR at FCS

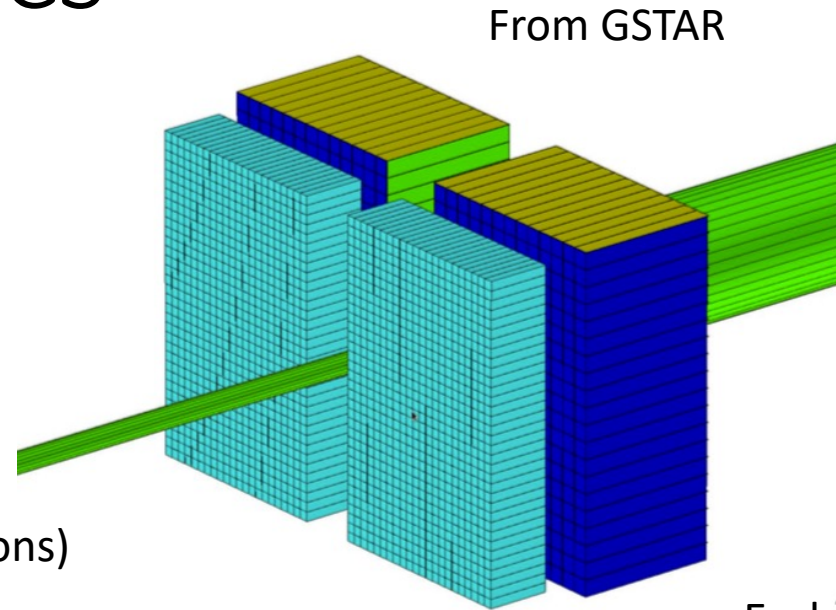
Ecal 34x22x2 = 1496ch of Phenix+PbSci
4 SiPM per Tower
~1500 pixels/GeV
Operated at low Vov (-0.5V ~ -1.0V)
On FEEBd attenuated (x 1/5)

Hcal 20x13x2 = 520ch of Fe+Scinti
6 SiPM per Tower
~180 pixels/GeV (1.5GeV & 270 pixels for muons)
Operated at high Vov (~ +0.5V)
On FEEBd attenuator not used

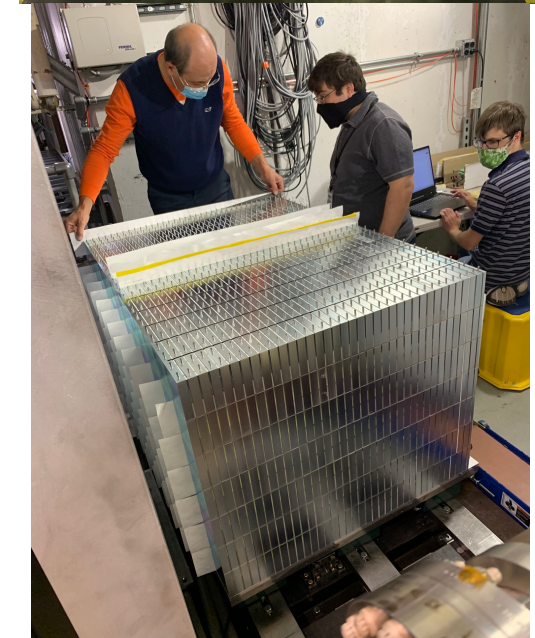
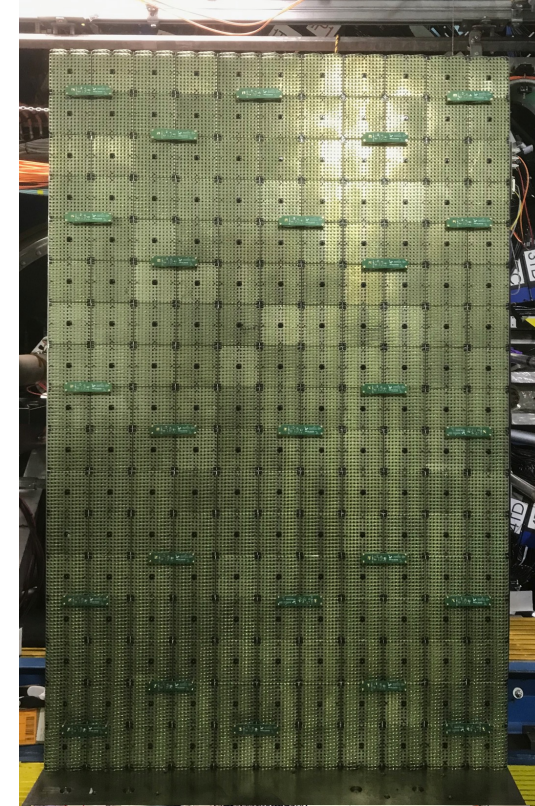
SiPM Hamamatsu S12572 3x3 mm² 15um
SiPM bd + FEEBd attached to detector
DEP board (ADC + DAQ + Trigger on FPGA + Slow Control) on floor, 8 time bins per RHIC clock
LED monitor system shining at "back" side of detector

Both Ecal and Hcal set to have 5.3MeV/ADC ch
ET equiv of 0.02MeV/ch (near beam) ~ 0.15MeV/ch (far beam)
At trigger 30MeV/count (drop low 7bits)

Run22 (pp510) radiation dose was expected to be roughly 5×10^{11} (~Run17)



Ecal 3

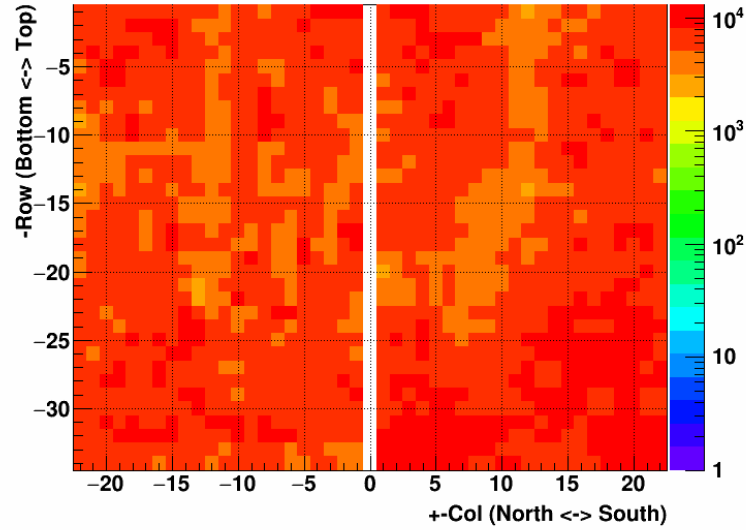


Hcall

STAR LED Monitor

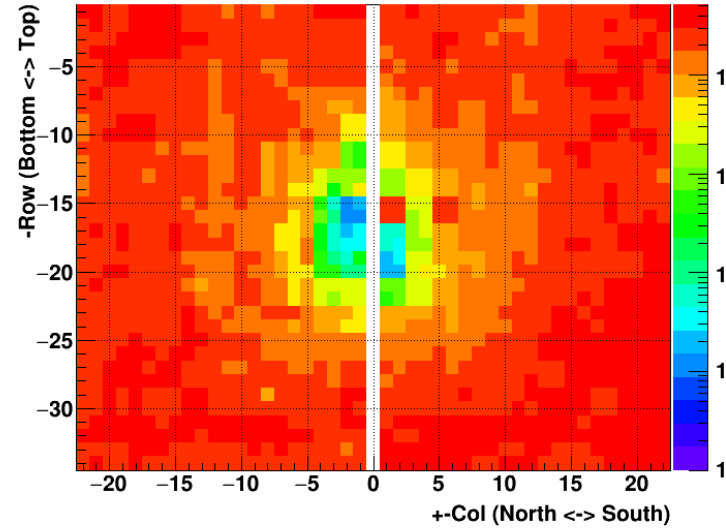
LED run early run22

Ecal View from Back



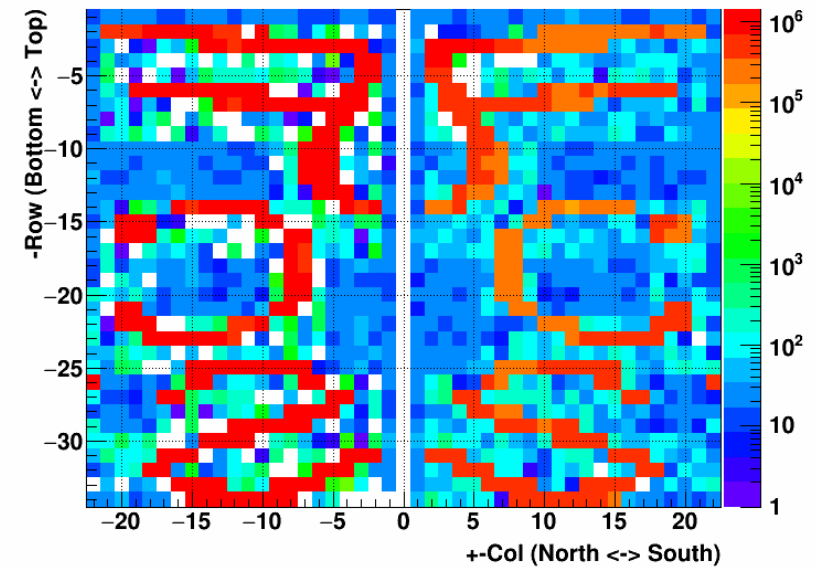
LED run late run22

Ecal View from Back

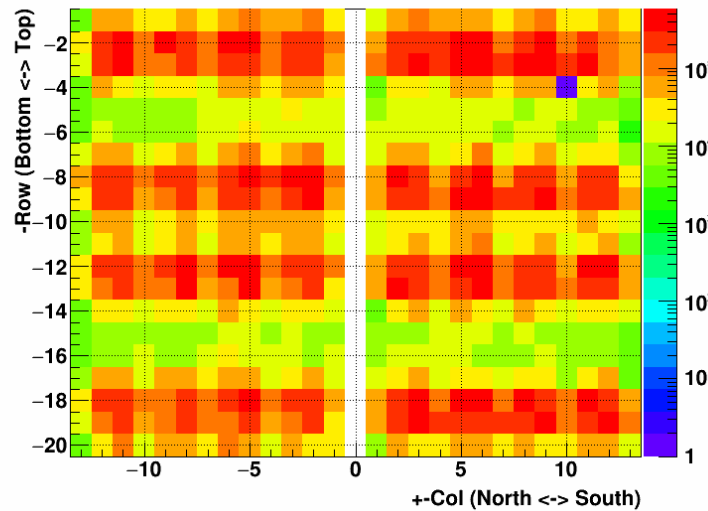


Map checking LED run with HV patterns

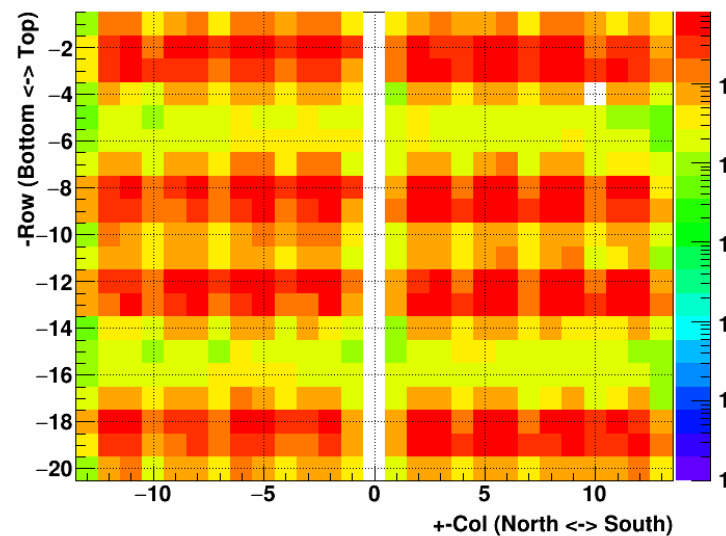
Ecal View from Back



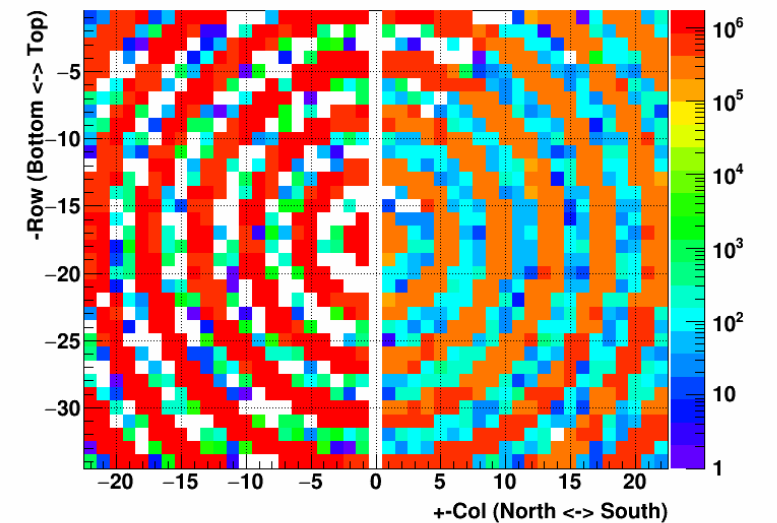
Hcal View from Back



Hcal View from Back



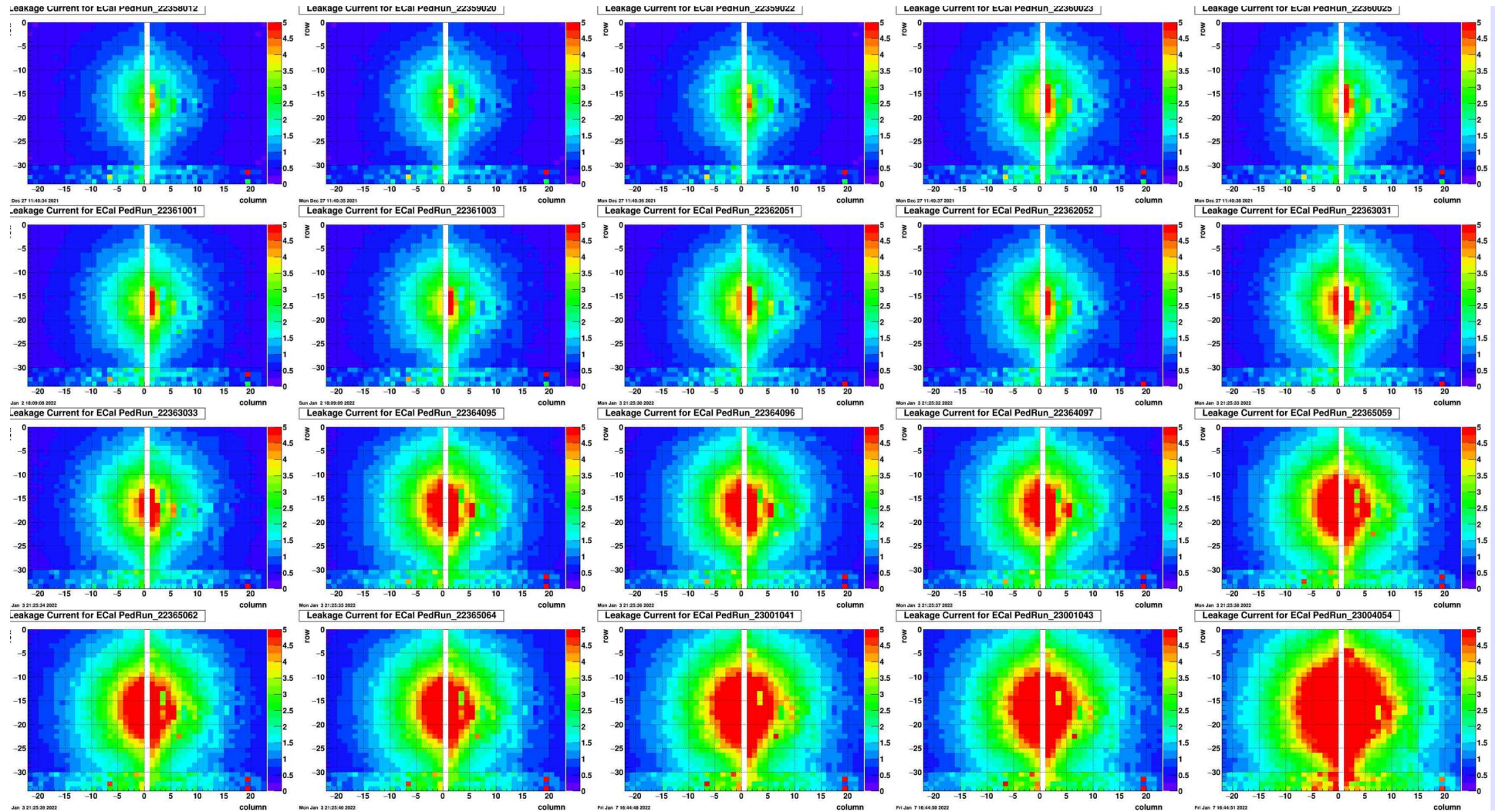
Ecal View from Back



SiPM Dark Current Monitor

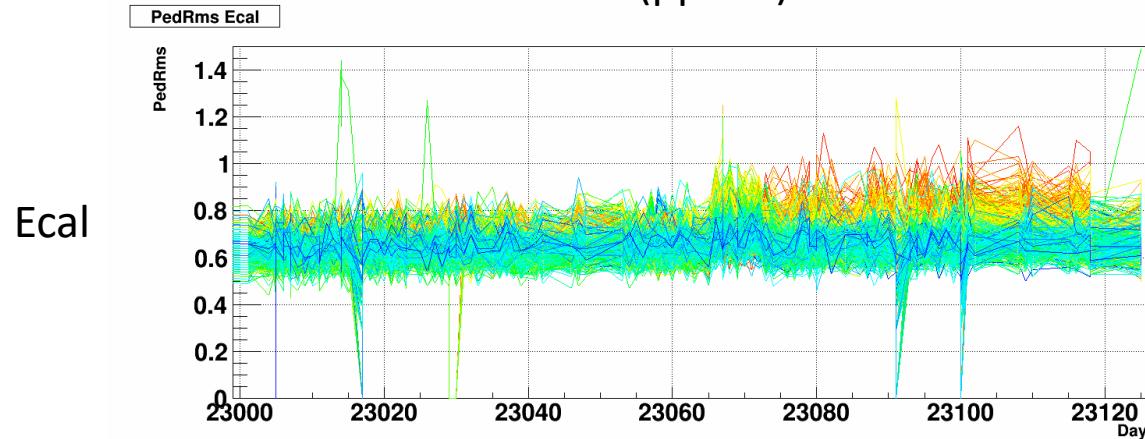
No beam @ operating voltage

Currents from SiPMs are recorded at beginning of each run

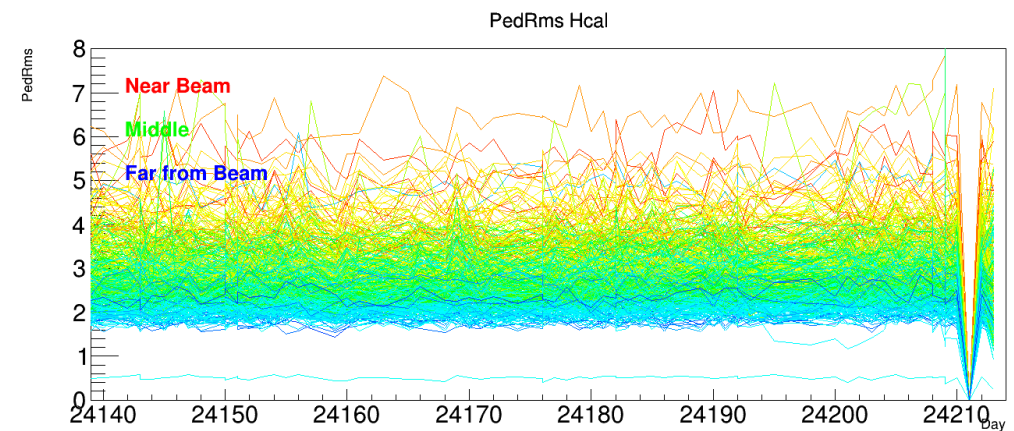
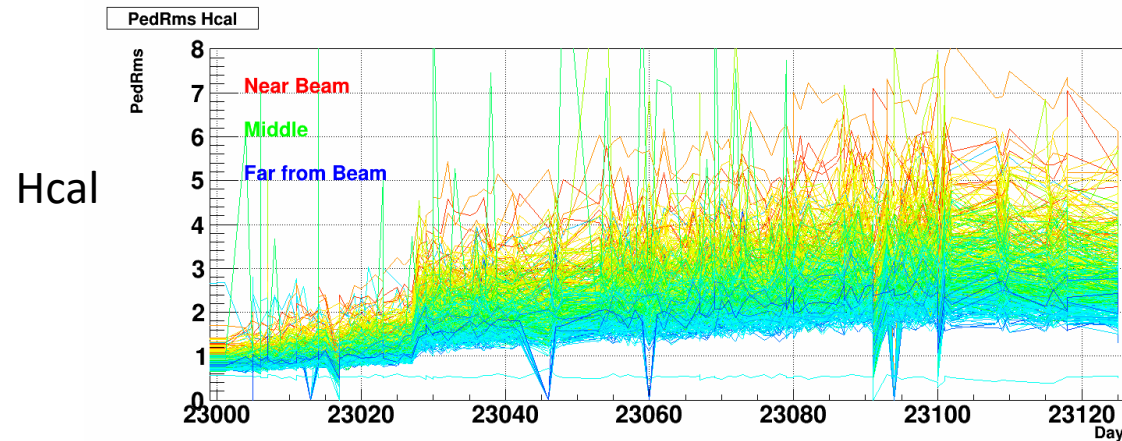
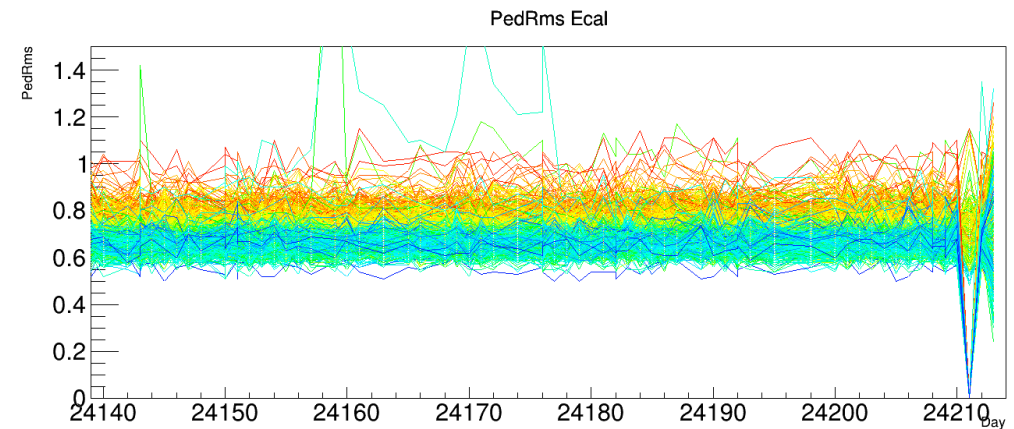


Pedestal RMS History

Run22 (pp510)

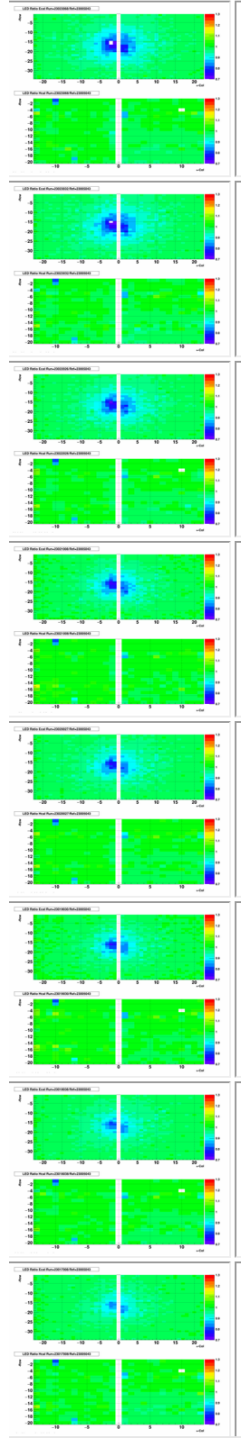


Run23 (AuAu200)



ECAL with more lights/GeV, operated at lower voltages, with 1/5 attenuation on FEEBd, see no effect on Pedestal RMS
Hcal with less lights, operated at higher voltages (no attenuation) see increase in pedestal RMS as it accumulates radiation damages

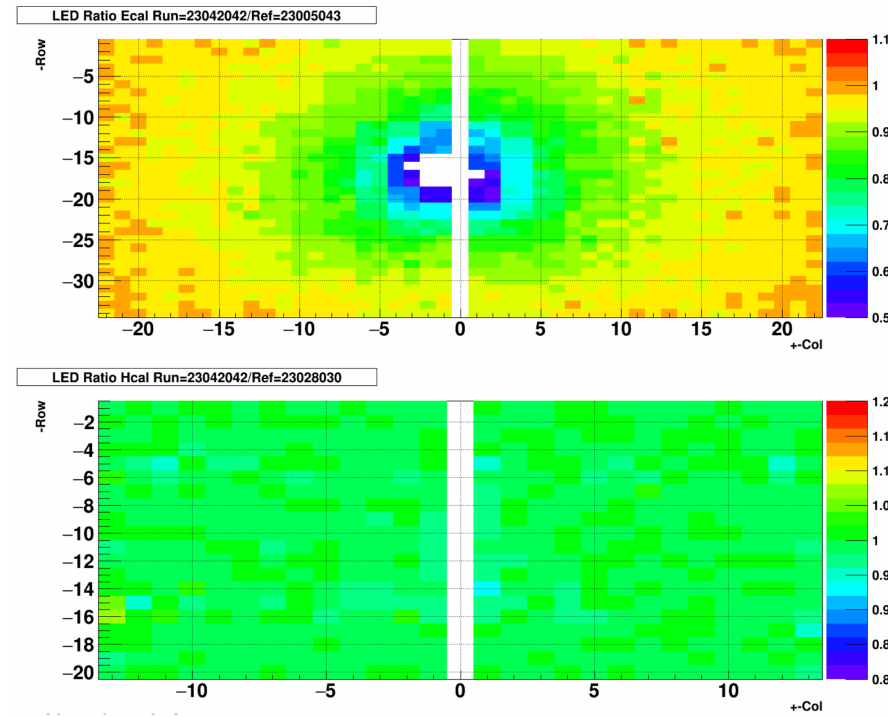
Radiation damages in something else : FEEBd



1/23

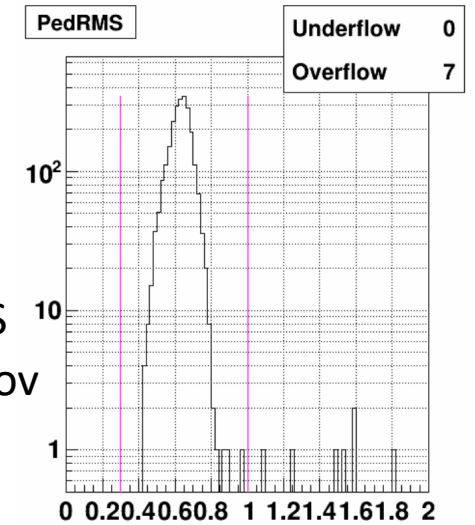
1/17

LED Ratio plot 2/11 over 1/05

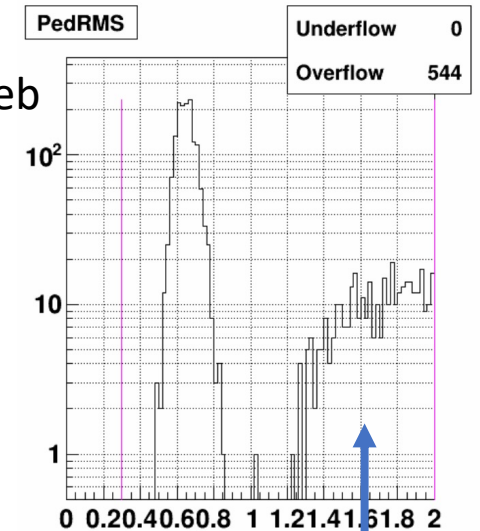


- Ecal loosing gains as much as $\sim 50\%$ near beam over a month
- Hcal is stable
- Pedestal RMS is still $< 1\text{ch}$, even near beam

Pedestal RMS
2021 Nov



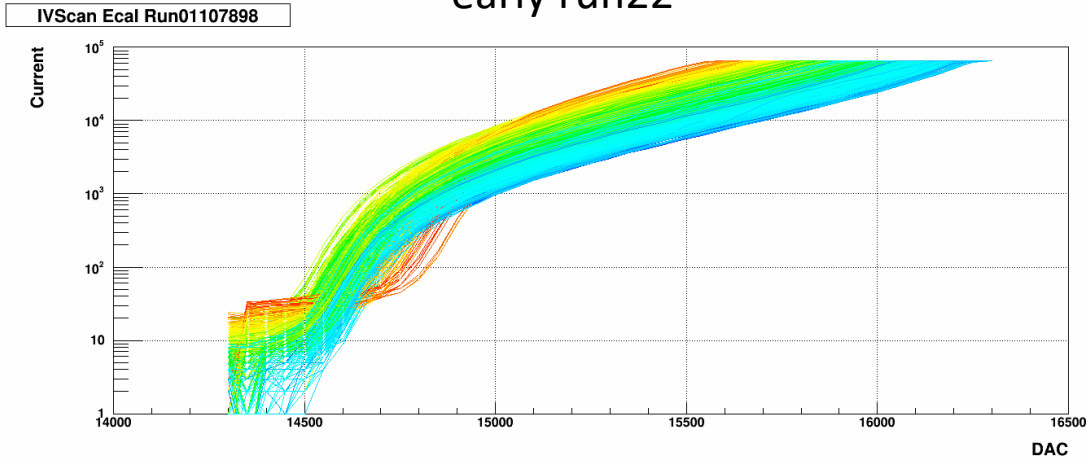
2002 Feb



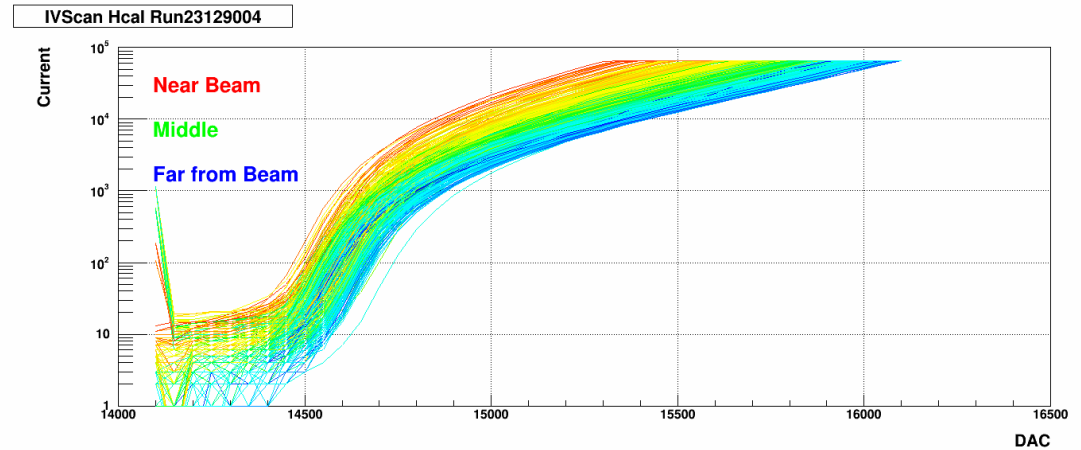
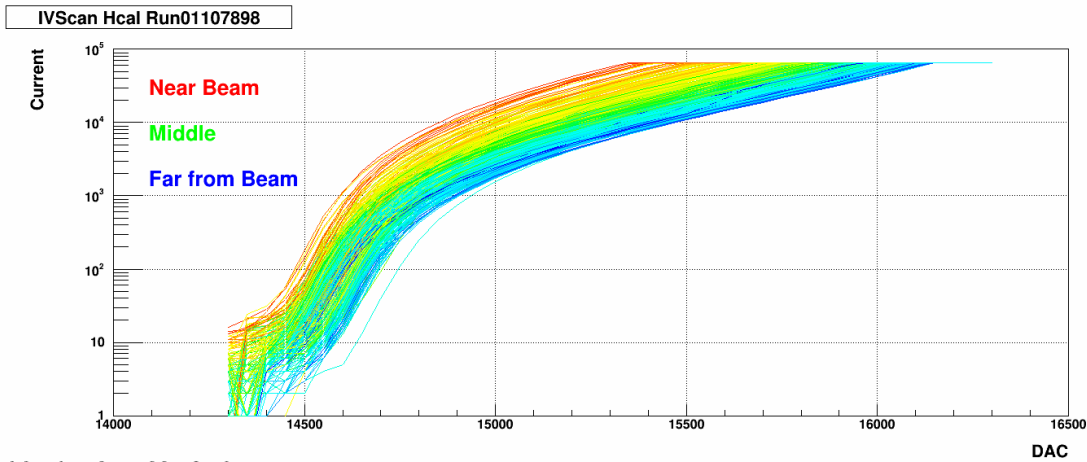
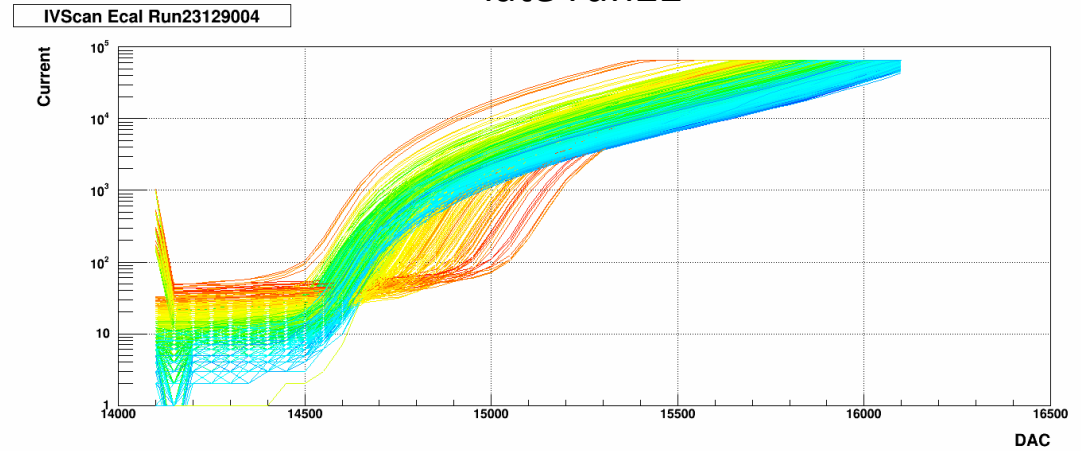
EPD

Weekly IV scan run

early run22

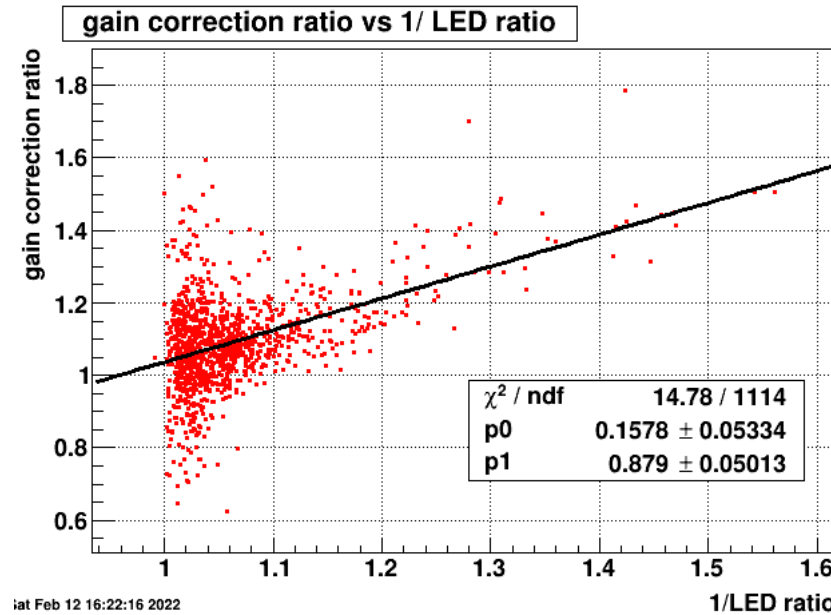
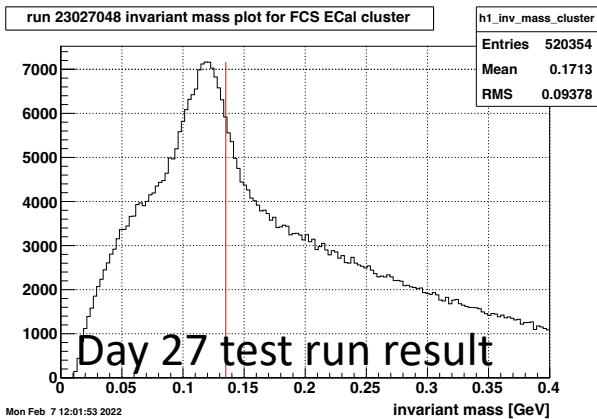
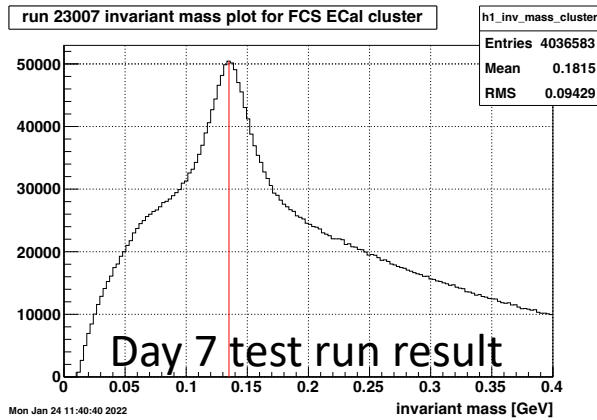


late run22



Ecal Near beam (Red) shows IV curve shifted to right

Gain loss confirmed by fast-offline Pi0 calibration



Between day7 and day27:

1/LED ratio

VS

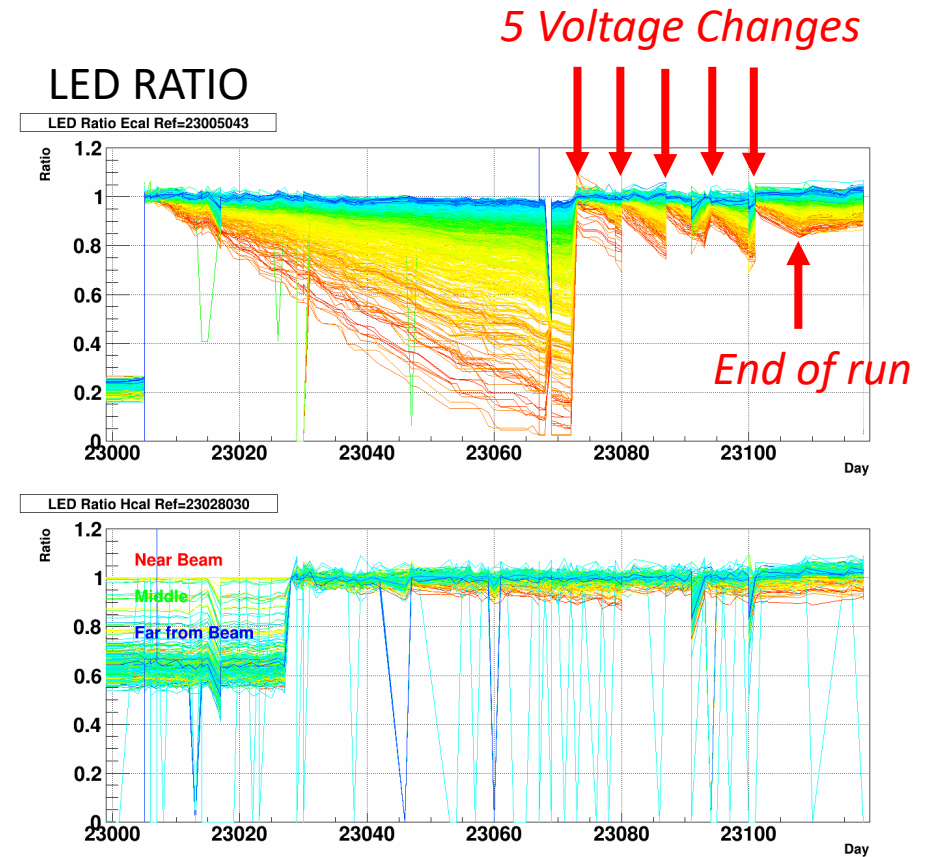
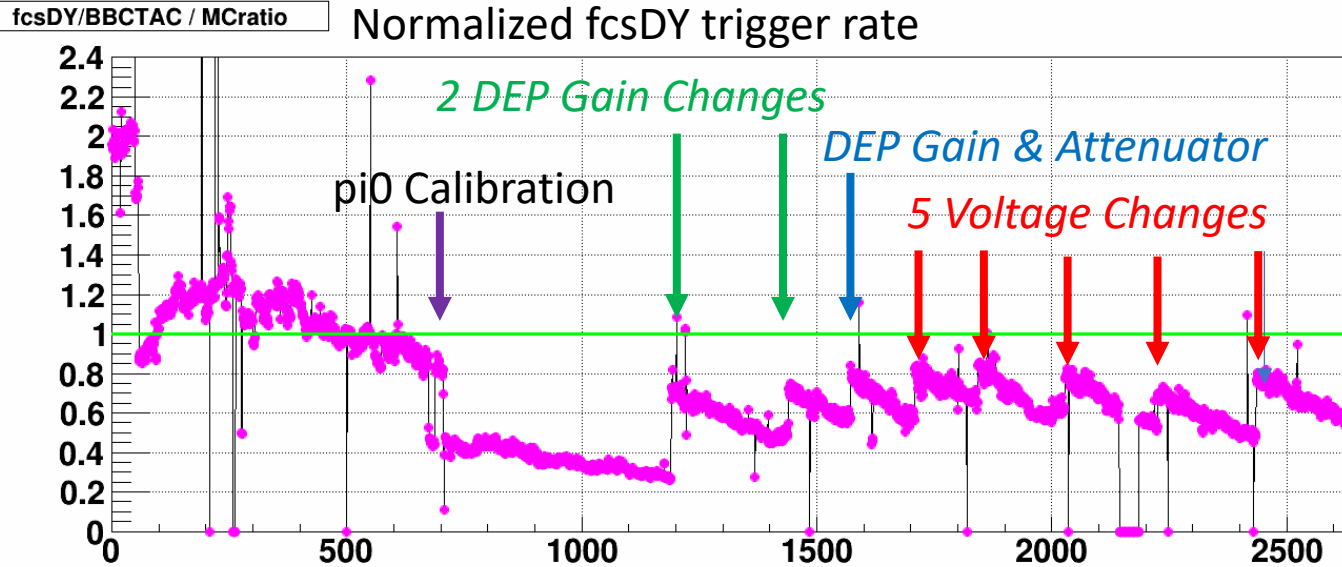
GainCorrectoon factor ratio

- Light loss seen in LED is also confirmed by Pi0 analysis
- LED and EM shower (pi0) see similar amount of light loss (not trivial)
- But variation is large (cannot use LED ratio for tower by tower gain)
- ASAP, we need to install tower by tower gain (electronics gain file) for DEP (trigger)

- More low-luminosity MB trigger calibration runs?
- Or physics data taking is enough?

FeeBd Radiation damage during Run22

- Significant radiation damage, losing $\sim 20\%$ signal / week @ Ecal near beam
- Compensating signal loss
 - Jan~Feb : “DEP gain” for triggering only
 - Early March: Reduce “FEEBd Attenuator”
 - March~ : “voltage” change based on LED ratios



Radiation Damage on Voltage Reference chip (AD # ADR392) on FEEBd

~2% drop on VREF slope after Run22

No change in offsets

$V = V_{br} + V_{ov}$ and **SiPM Gain $\sim V_{ov}^2$**

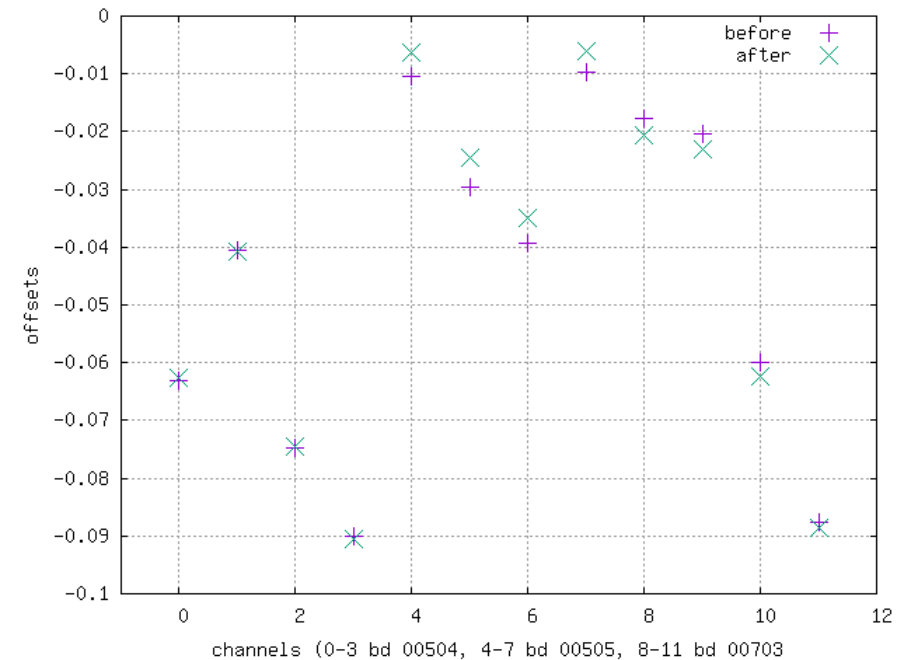
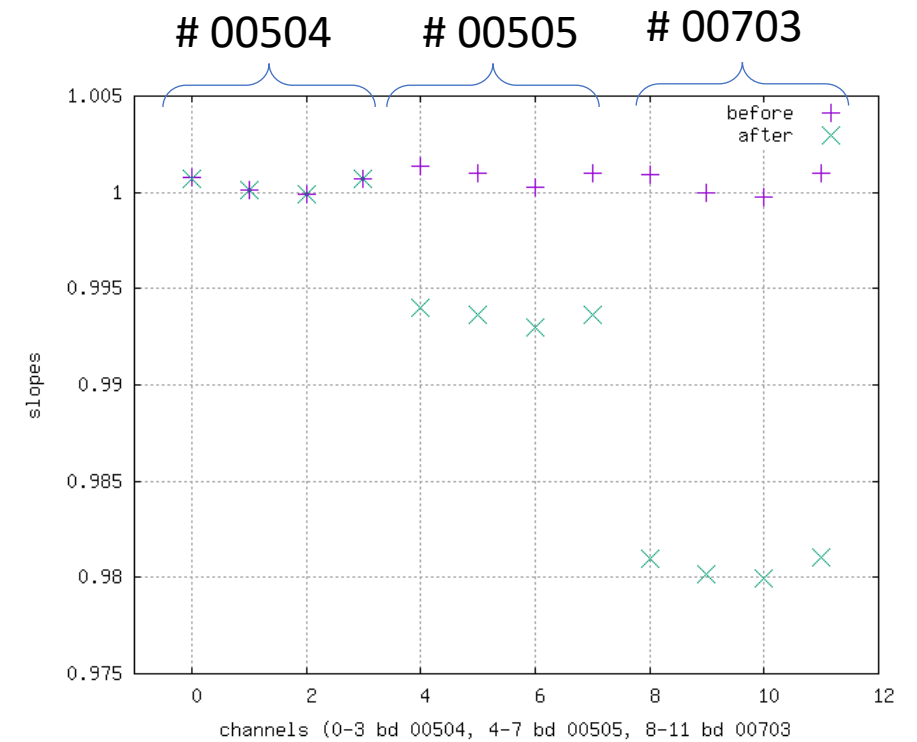
61.5V = 60V + 1.5V

↓ **losing 2% in reference voltage**

60.3V = 60V + 0.3V

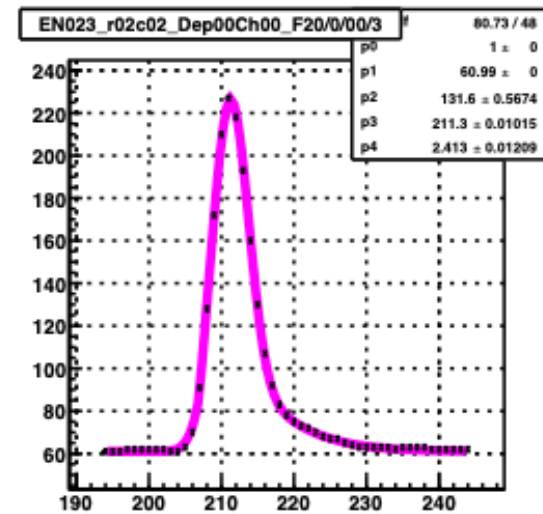
Gerard Visser : “In ePIC, I am probably thinking to have the V reference chip external, mounted at patchpanel board type of location at outer radius of the detector, to reduce its radiation damage. But I am still tbd and potentially I learn of a suitably radhard reference to use on the FEE board directly. I know I definitely won't use the type I used in FCS!”

Oleg Tsai: “the same chip for Ref. Voltage we used during prototyping in Run17, and at that time we have not seen degradation of that chip. So irradiation tests people are doing for electronics may need to be done on ‘production’ chips.”

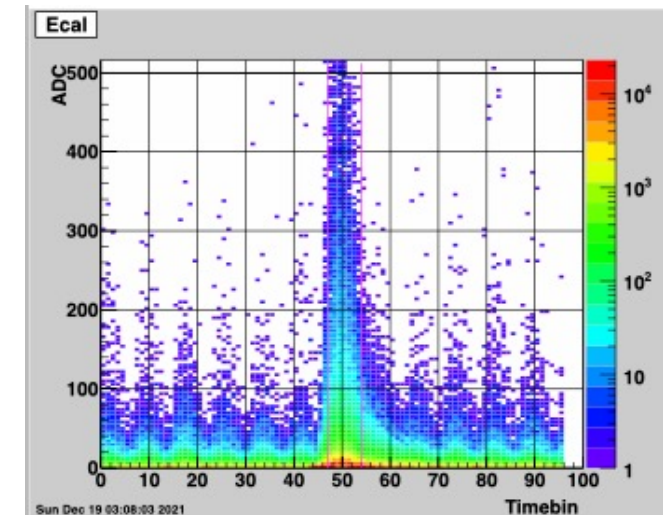


Summary

- STAR FCS saw 2 kinds of radiation damages
- Radiation damages on SiPM
 - Noise (dark current) increased
 - Hcal pedestal RMS increased (not much Ecal)
 - Possible slight (<10%) hint gain loss in Hcal, but hard to separate from FeeBd gain loss
- Radiation damage on FeeBd voltage reference chip
 - ~2% loss of slope after Run22 (pp510), which is >90% reduction on Vov, for Ecal
 - We compensated using DEP gain (trigger only), FeeBd attenuator and adjusting voltage based on LED
 - Much less effects on Hcal
 - Less gamma? Ecal FEEBds are in front of Ecal, and Hcal FEEbd are in back of Ecal and Hcal
 - We operated Hcal at much larger Vov
- Very important to monitor
 - SiPM dark currents
 - Pedestal and its RMS
 - LED
 - Trigger Rates
 - Fast offline calibration
 - Occasional IV-curve scan



Single LED pulse vs time bin with fits (purple)



Pulse shapes vs time bin from many events overlapped during pp 510 physics running

What should we maybe expect on radiation effects on a voltage reference?

- I did not yet find anything online for the chip we are using (AD # ADR392)
- The datasheet for an example radiation-hard chip's (ST # RHF1009A) shows a typical 0.1% decrease in Vref for 300 krad (gamma).
 - BTW probably unaffordable anyways, it's meant for space hardware
- We see 2% decrease, for some unknown dose – any dose guesses?
- Perhaps expect on the order of 1% decrease at 200 krad for “generic” (but older) reference IC's, according to this paper

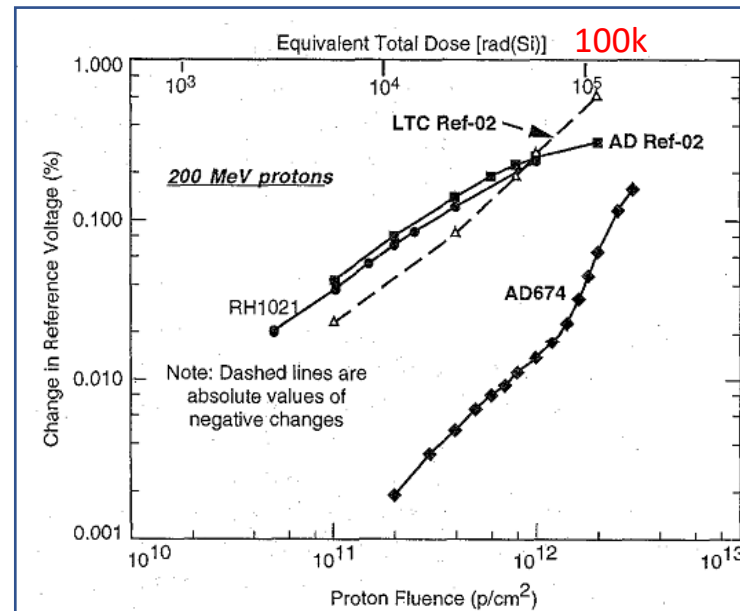


Figure 5. Proton Degradation of Moderate-Precision Reference Devices

protons. neutrons can be much worse than γ

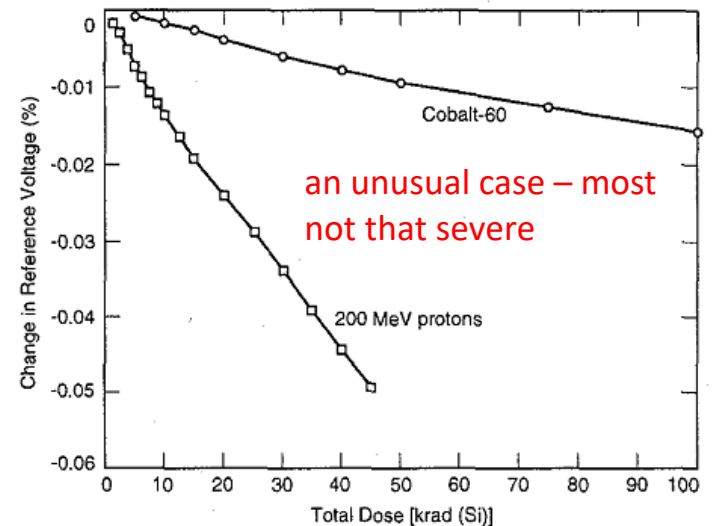


Figure 1. Comparison of the Effects of Proton and Gamma Radiation on Degradation of the AD2710 Precision Reference

B. G. Rax, C. I. Lee and A. H. Johnston, "Degradation of precision reference devices in space environments," in *IEEE Transactions on Nuclear Science*, vol. 44, no. 6, pp. 1939-1944, Dec. 1997, doi: 10.1109/23.658965.